

## Transistors

## General purpose amplification(−12V, −2A)

## 2SB1730

## ●Applications

Low frequency amplifier

Deiver

## ●Features

1) A collector current is large.

2) Collector saturation voltage is low.

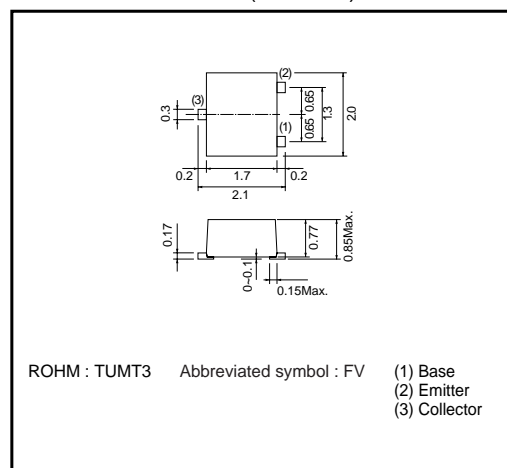
$$V_{CE(sat)} \leq -180\text{mV}$$

at  $I_C = -1\text{A}$  /  $I_B = -50\text{mA}$ 

## ●Packaging specifications

| Type    | Package                      | Taping |
|---------|------------------------------|--------|
|         | Code                         | TL     |
|         | Basic ordering unit (pieces) | 3000   |
| 2SB1730 |                              | ○      |

## ●External dimensions (Unit : mm)



## ●Absolute maximum ratings (Ta=25°C)

| Parameter                   | Symbol    | Limits      | Unit |
|-----------------------------|-----------|-------------|------|
| Collector-base voltage      | $V_{CBO}$ | −15         | V    |
| Collector-emitter voltage   | $V_{CEO}$ | −12         | V    |
| Emitter-base voltage        | $V_{EBO}$ | −6          | V    |
| Collector current           | $I_C$     | −2          | A    |
|                             | $I_{CP}$  | −4          | A*   |
| Collector power dissipation | $P_C$     | 400         | mW   |
| Junction temperature        | $T_j$     | 150         | °C   |
| Storage temperature         | $T_{stg}$ | −55 to +150 | °C   |

\* Single pulse  $P_w=1\text{ms}$ 

## ●Electrical characteristics (Ta=25°C)

| Parameter                            | Symbol        | Min. | Typ. | Max. | Unit | Conditions   |
|--------------------------------------|---------------|------|------|------|------|--|
| Collector-base breakdown voltage     | $BV_{CBO}$    | −15  | —    | —    | V    | $I_C = -10\mu\text{A}$   |
| Collector-emitter breakdown voltage  | $BV_{CEO}$    | −12  | —    | —    | V    | $I_C = -1\text{mA}$  |
| Emitter-base breakdown voltage       | $BV_{EBO}$    | −6   | —    | —    | V    | $I_E = -10\mu\text{A}$   |
| Collector cutoff current             | $I_{CBO}$     | —    | —    | −100 | nA   | $V_{CB} = -15\text{V}$   |
| Emitter cutoff current               | $I_{EBO}$     | —    | —    | −100 | nA   | $V_{EB} = -6\text{V}$  |
| Collector-emitter saturation voltage | $V_{CE(sat)}$ | —    | −120 | −180 | mV   | $I_C = -1\text{A}$ , $I_B = -50\text{mA}$                            |
| DC current transfer ratio            | $h_{FE}$      | 270  | —    | 680  | —    | $V_{CE} = -2\text{V}$ , $I_C = -200\text{mA}$ *                      |
| Transition frequency                 | $f_T$         | —    | 360  | —    | MHz  | $V_{CE} = -2\text{V}$ , $I_E = 200\text{mA}$ , $f = 100\text{MHz}$ * |
| Output capacitance                   | $C_{ob}$      | —    | 15   | —    | pF   | $V_{CB} = -10\text{V}$ , $I_E = 0\text{mA}$ , $f = 1\text{MHz}$      |

\* Pulsed

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## ●Electrical characteristic curves

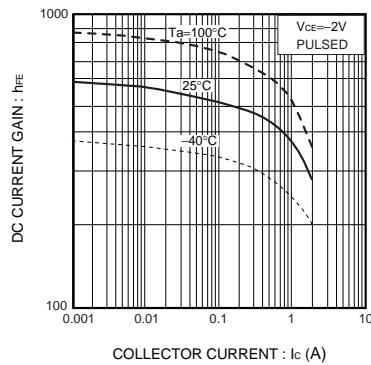


Fig.1 DC current gain vs. collector current

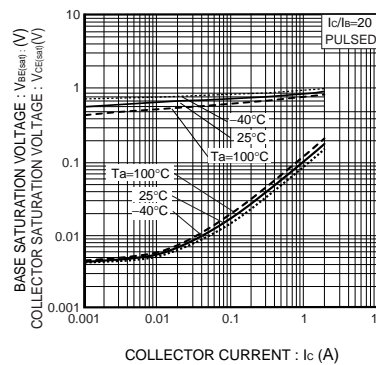


Fig.2 Collector-emitter saturation voltage vs. collector current

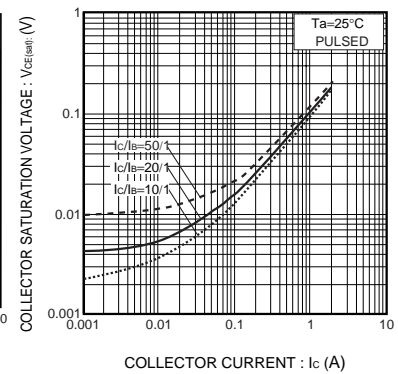


Fig.3 Collector-emitter saturation voltage vs. collector current

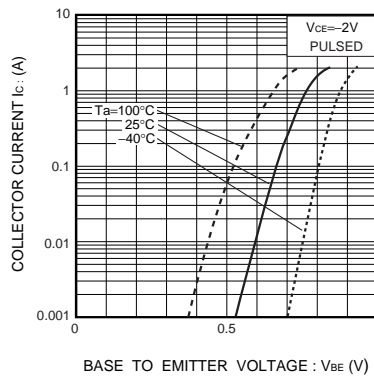


Fig.4 Grounded emitter propagation characteristics

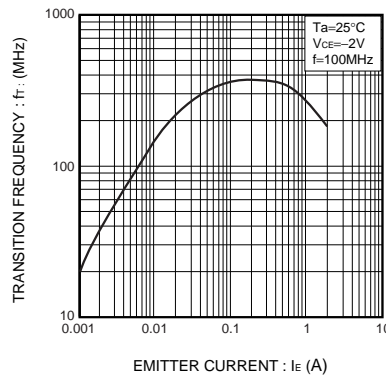


Fig.5 Gain bandwidth product vs. emitter current

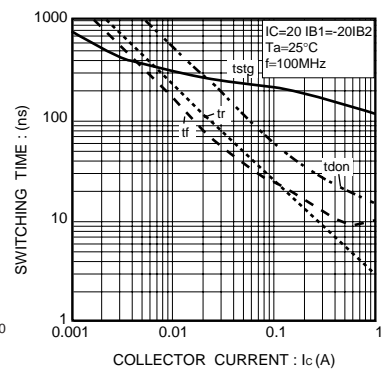
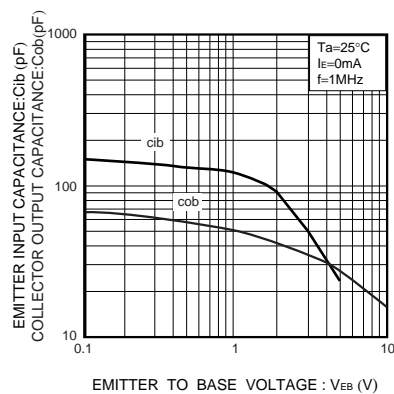


Fig.6 Switching time

Fig.7 Collector output capacitance vs. collector-base voltage  
Emitter input capacitance vs. emitter-base voltage

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